# MPSW05, MPSW06

MPSW06 is a Preferred Device

# **One Watt Amplifier Transistors**

## **NPN Silicon**

### Features

• Pb-Free Packages are Available\*

#### MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Collector – Emitter Voltage	MPSW05 MPSW06	V <sub>CEO</sub>	60 80	Vdc
Collector-Base Voltage	MPSW05 MPSW06	V <sub>CBO</sub>	60 80	Vdc
Emitter-Base Voltage		$V_{\text{EBO}}$	4.0	Vdc
Collector Current – Continuous	6	۱ <sub>C</sub>	500	mAdc
Total Device Dissipation @ $T_A$ Derate above 25°C	= 25°C	PD	1.0 8.0	W mW/°C
Total Device Dissipation @ T <sub>C</sub> Derate above 25°C	= 25°C	PD	2.5 20	W m₩/°C
Operating and Storage Junctio Temperature Range	n	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

### THERMAL CHARACTERISTICS

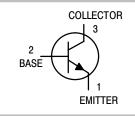
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



## **ON Semiconductor®**

#### http://onsemi.com







MPSW0x =Device Code

	x = 5 or 6
А	=Assembly Location
Y	=Year
WW	=Work Week
•	=Pb-Free Package
Joto Migrada	at may be in either location

(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MPSW05	TO-92	5,000 Units/Box
MPSW05G	TO-92 (Pb-Free)	5,000 Units/Box
MPSW06	TO-92	5,000 Units/Box
MPSW06G	TO-92 (Pb-Free)	5,000 Units/Box
MPSW06RLRA	TO-92	2,000/Tape & Reel
MPSW06RLRAG	TO–92 (Pb–Free)	2,000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**Preferred** devices are recommended choices for future use and best overall value.

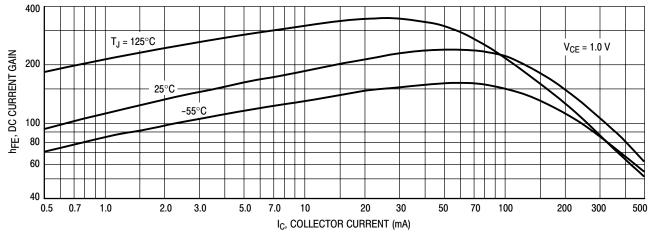
\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## MPSW05, MPSW06

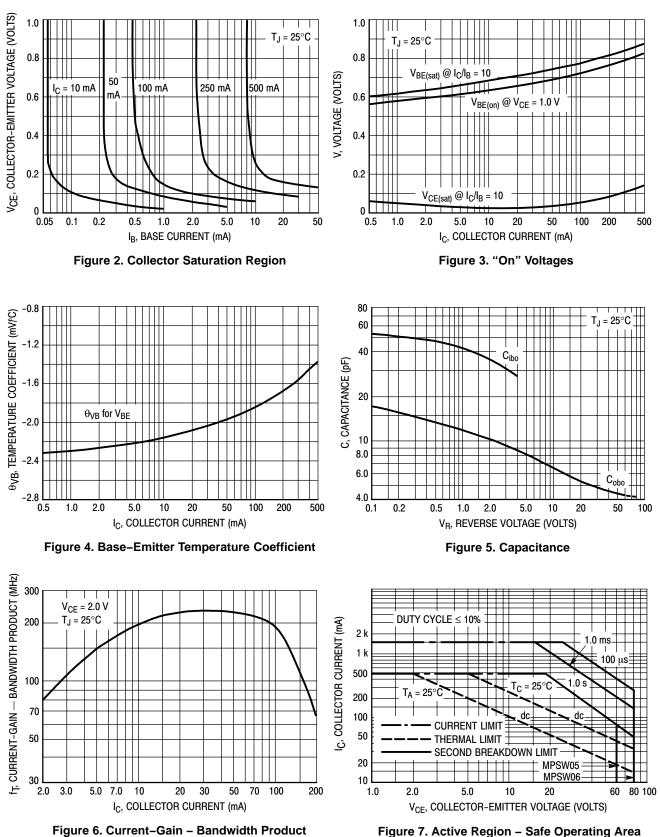
## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 1) ( $I_C = 1.0 \text{ mAdc}, I_B = 0$ )	MPSW05 MPSW06	V <sub>(BR)CEO</sub>	60 80		Vdc
Emitter – Base Breakdown Voltage $(I_E = 100 \ \mu Adc, I_C = 0)$		V <sub>(BR)EBO</sub>	4.0	-	Vdc
Collector Cutoff Current $(V_{CE} = 40 \text{ Vdc}, I_B = 0)$ $(V_{CE} = 60 \text{ Vdc}, I_B = 0)$	MPSW05 MPSW06	ICES		0.5 0.5	μAdc
Collector Cutoff Current $(V_{CB} = 40 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$	MPSW05 MPSW06	I <sub>CBO</sub>		0.1 0.1	μAdc
Emitter Cutoff Current ( $V_{EB} = 3.0 \text{ Vdc}, I_C = 0$ )		I <sub>EBO</sub>	-	0.1	μAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain (I <sub>C</sub> = 50 mAdc, V <sub>CE</sub> = 1.0 Vdc) (I <sub>C</sub> = 250 mAdc, V <sub>CE</sub> = 1.0 Vdc)		h <sub>FE</sub>	80 60		-
Collector – Emitter Saturation Voltage ( $I_C = 250 \text{ mAdc}, I_B = 10 \text{ mAdc}$ )		V <sub>CE(sat)</sub>	-	0.4	Vdc
Base-Emitter Saturation Voltage (I <sub>C</sub> = 250 mAdc, V <sub>CE</sub> = 5.0 Vdc)		V <sub>BE(sat)</sub>	-	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS		-	•		•
Current-Gain – Bandwidth Product ( $I_C$ = 200 mAdc, $V_{CE}$ = 5.0 Vdc, f = 20 MHz)		f <sub>T</sub>	50	-	MHz
Output Capacitance (V <sub>CB</sub> = 10 V, f = 1.0 MHz)		C <sub>obo</sub>	-	12	pF

1. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.

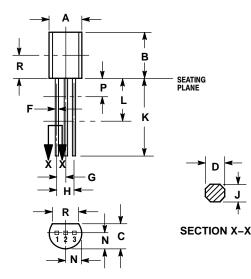






#### PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-10 ISSUE AL



1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

NOTES

- CONTROLLING DIMENSION: INCH.
  CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- IS UNCONTROLLED. 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSIONS D AND J APPLY BETWEEN L AND K MIMIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.44	5.21	
В	0.290	0.310	7.37	7.87	
С	0.125	0.165	3.18	4.19	
D	0.018	0.021	0.457	0.533	
F	0.016	0.019	0.407	0.482	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
ſ	0.018	0.024	0.46	0.61	
κ	0.500		12.70		
L	0.250		6.35		
Ν	0.080	0.105	2.04	2.66	
Ρ		0.100		2.54	
R	0.135		3.43		

STYLE 1: PIN 1. EMITTER

2. BASE

3. COLLECTOR

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